

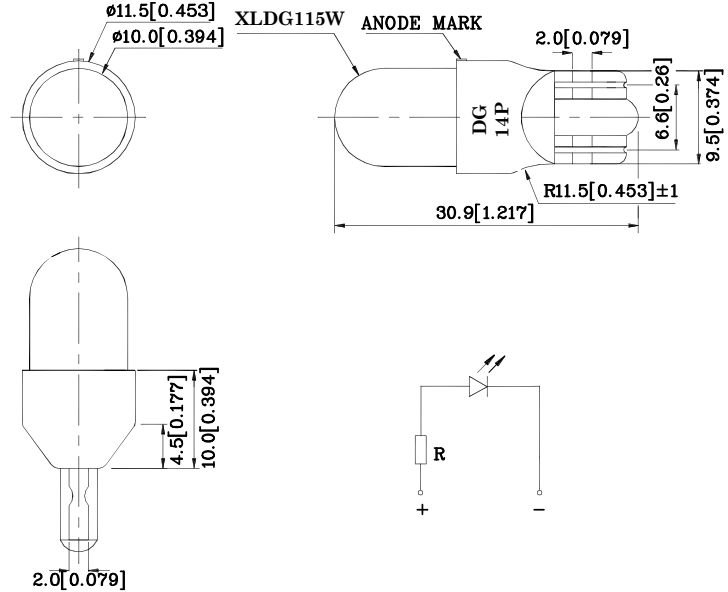
Features

- Long life and robust package
- Low power consumption
- Vibration resistant
- 14V internal resistor
- RoHS Compliant



ATTENTION
OBSERVE PRECAUTIONS
FOR HANDLING
ELECTROSTATIC
DISCHARGE
SENSITIVE
DEVICES

Package Schematics



Notes:

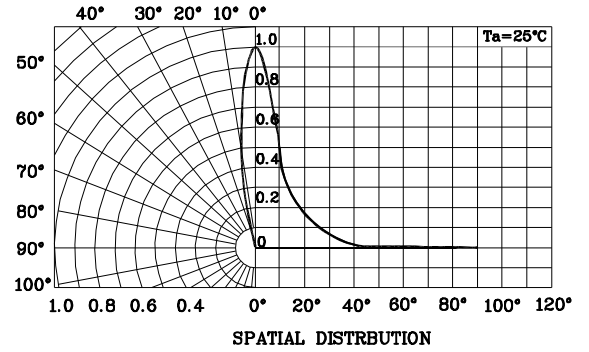
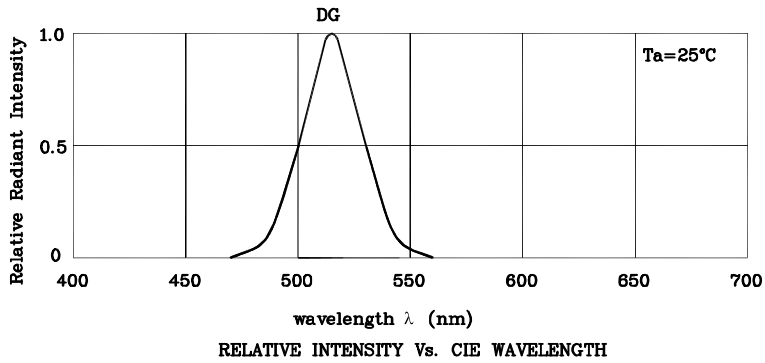
1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
3. Specifications are subject to change without notice.

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$)		DG (InGaN)	Unit
Reverse Voltage	V_R	5	V
Forward Voltage	V_F	16	V
Power Dissipation	P_D	256	mW
Operating Temperature	T_A	-40 ~ +70	°C
Storage Temperature	T_{stg}	-40 ~ +85	
Electrostatic Discharge Threshold (HBM)		450	v
Lead Solder Temperature [2mm Below Package Base]	260°C For 3 Seconds		
Lead Solder Temperature [5mm Below Package Base]	260°C For 5 Seconds		

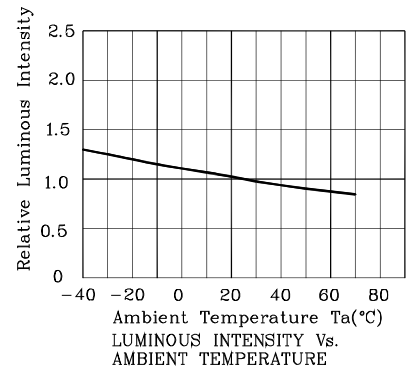
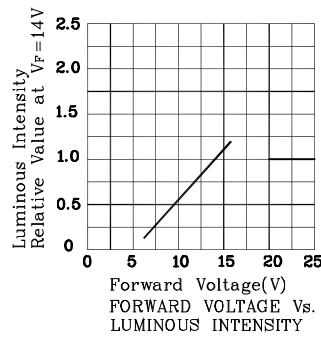
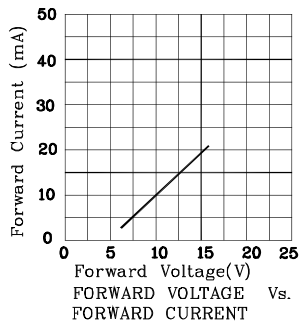
Operating Characteristics ($T_A=25^\circ\text{C}$)		DG (InGaN)	Unit
Forward Current (Typ.) ($V_F=14\text{V}$)	I_F	16	mA
Forward Current (Max.) ($V_F=14\text{V}$)	I_F	21	mA
Reverse Current (Max.) ($V_R=5\text{V}$)	I_R	50	uA
Wavelength of Peak Emission CIE127-2007*(Typ.) ($V_F=14\text{V}$)	λ_P	515*	nm
Wavelength of Dominant Emission CIE127-2007* (Typ.) ($V_F=14\text{V}$)	λ_D	525*	nm
Spectral Line Full Width At Half-Maximum (Typ.) ($V_F=14\text{V}$)	$\Delta\lambda$	30	nm

Part Number	Emitting Color	Emitting Material	Lens-color	Luminous Intensity CIE127-2007* ($V_F=14\text{V}$) mcd		Wavelength CIE127-2007* λ_P nm	Viewing Angle 20 1/2
				min.	typ.		
XYWDG101W14V	Green	InGaN	Water Clear	8000*	12000*	515*	20°

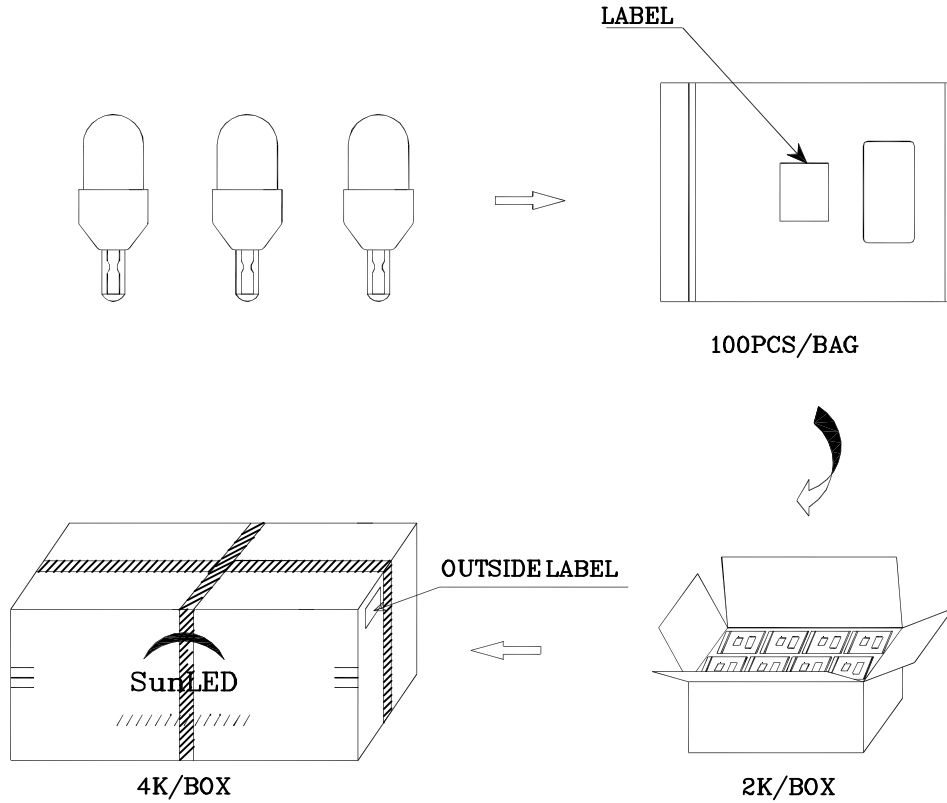
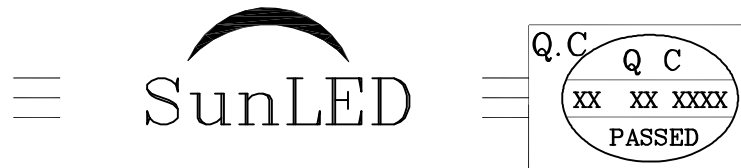
*Luminous intensity value and wavelength are in accordance with CIE127-2007 standards.




❖ DG



PACKING & LABEL SPECIFICATIONS

Q.C
Q C
XX XX XXXX
PASSED

P/N0 : XYWxxx101x	
QTY : 100 pcs	CODE: XXX
S/N : XX	
LOT NO:	
 xxxxxxxxxxxxxxxxxxxxxxxxxxxx	
RoHS Compliant	